

# Recent Analog X-ray Pixel Detector Developments



CHESS &amp; LASSP

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**Support: DOE, NIH**

- Description of PADs**
- Application examples**
- Mixed-Mode PAD**

# Basic Pixel Array Detector (PAD)



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## Diode Detection Layer

- Fully depleted, high resistivity
- Direct x-ray conversion
- Silicon, GaAs, CdTe, etc.

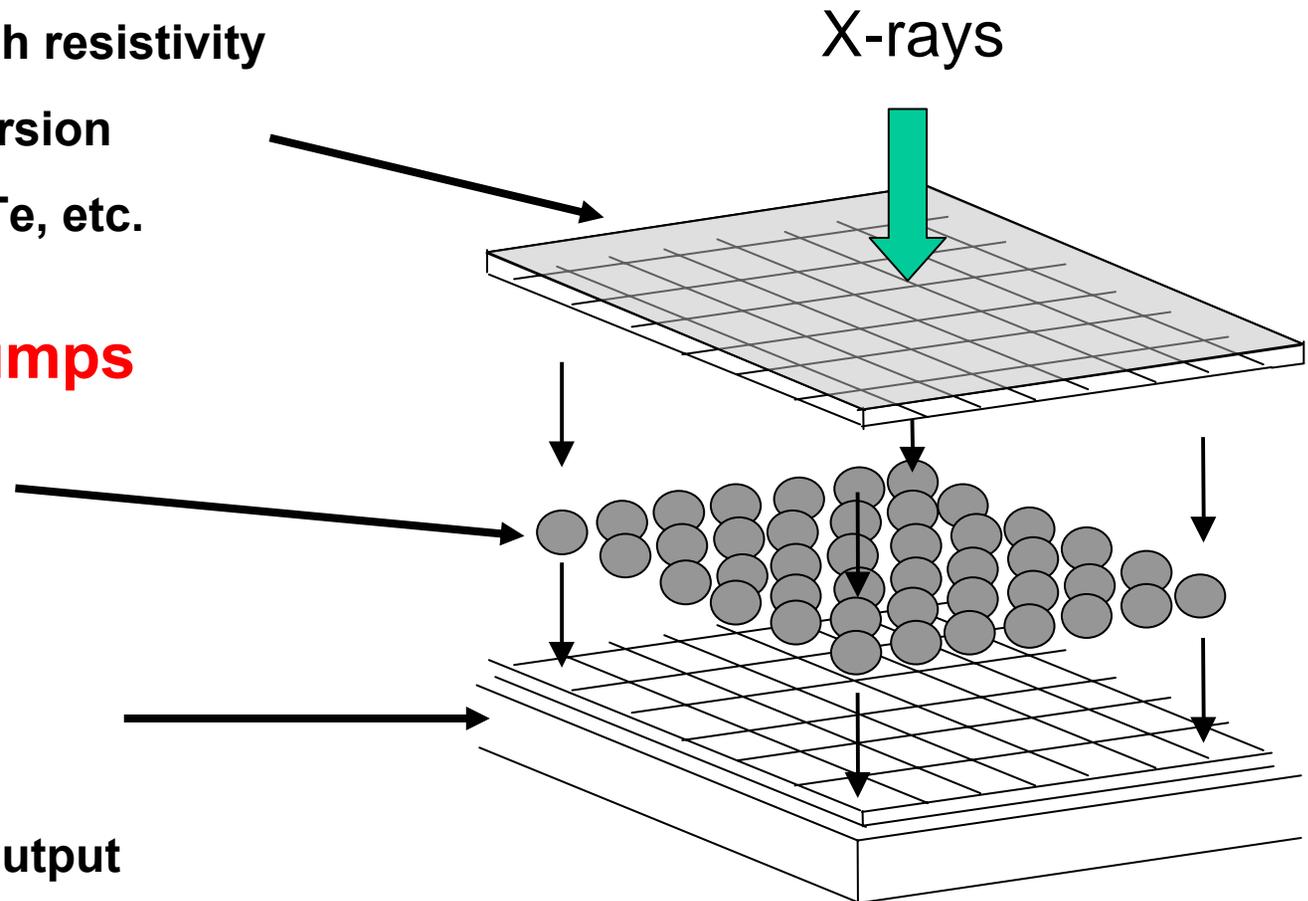
## Connecting Bumps

- Solder or indium
- 1 per pixel

## CMOS Layer

- Signal processing
- Signal storage & output

*Gives enormous flexibility!*





## Photon counting PADs

- Input amp, followed by shaper and threshold for photon discrimination to output a digital bit, usually to an in-pix counter.
- Pixel count-rate set by speed of electronics processing.  $10^6$  -  $10^8$  x-rays/sec typical. Susceptible to pile-up.
- Requires very careful noise control.
- “Well-depth” set by number of bits in counter.
- Duty cycle set by need to read in-pix counter if synchronous. If asynchronous, need to isolate input from coupling to digital readout.

## Analog PADs

- Input integrator onto in-pix analog storage. Reminiscent of CCD.
- For readout, buffer stored signal to off-pix (usually off-chip) ADC.
- Capable of handling enormous count-rate.
- Well-depth set by analog storage capacity.
- Duty cycle set by time to digitize analog signal if synchronous. If asynchronous, need to isolate input from coupling to analog readout.

# High Speed Imaging: Design Requirements



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## Rapid Framing Imager

In pix storage for 8 frames

Selectable integration time (1  $\mu\text{s}$  to seconds)

Deadtime  $< 1 \mu\text{s}$

Well-depth  $> 10^4$  x-rays/pixel/frame (for 1% statistics)

**Count rate**  $> 10^{10}$  x-rays/pixel/s  Analog integration needed

**Pixel size**  $\leq 150 \mu\text{m}$  square

**Standard CMOS fabrication service**

# Cornell Analog PAD



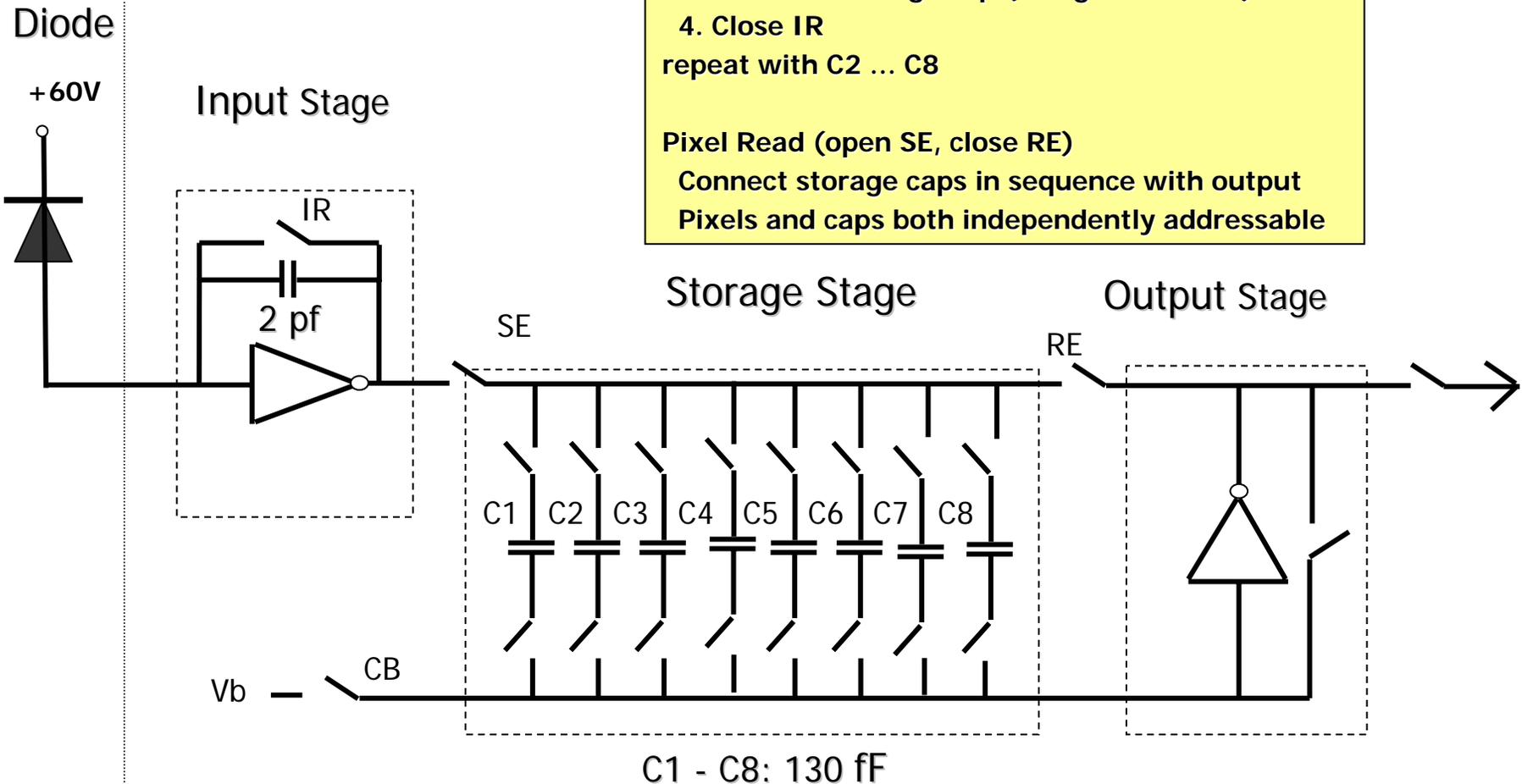
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Rapid framing (SE, IR closed)

1. select storage cap C1
  2. Open IR switch (Frame integration begins)
  3. Deselect Storage cap (Integration ends)
  4. Close IR
- repeat with C2 ... C8

Pixel Read (open SE, close RE)

Connect storage caps in sequence with output  
Pixels and caps both independently addressable



# Cornell 100x92 Analog PAD

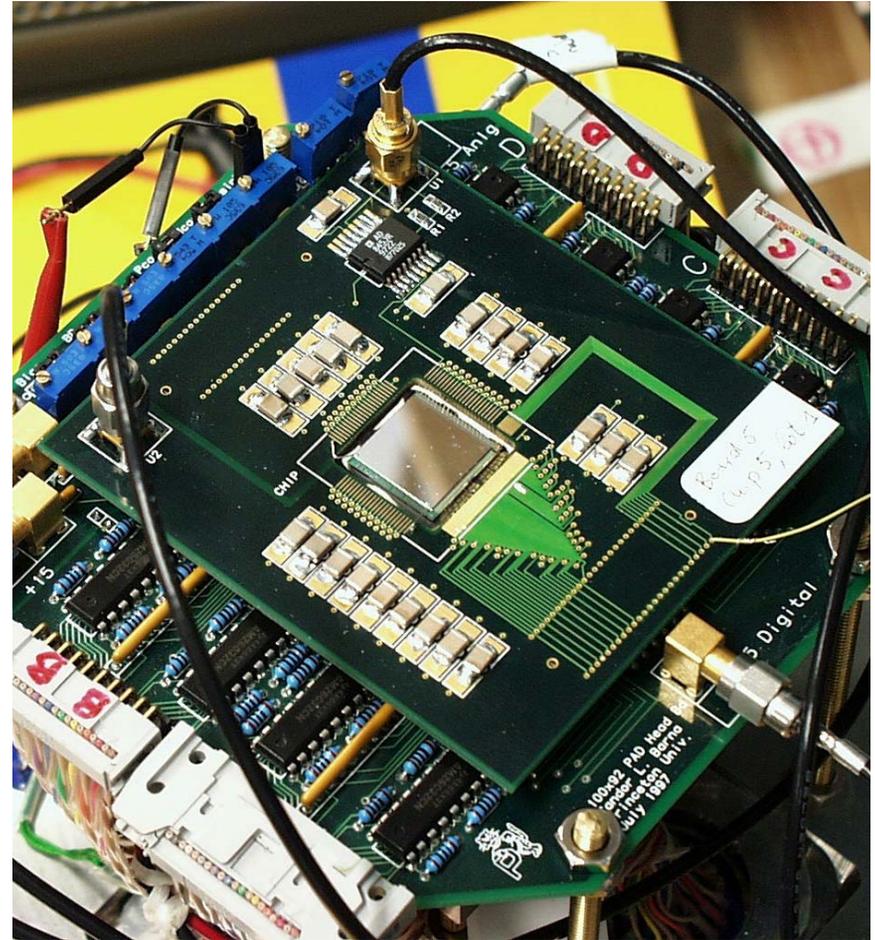


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- 1.2  $\mu\text{m}$  HP CMOS process (MOSIS)  
(Linearized Capacitors)
- 15 x 13.8 mm<sup>2</sup> active area; 100x92 pixels
- 150  $\mu\text{m}$  square pixel
- 300  $\mu\text{m}$  thick, high resistivity Si diode wafer (SINTEF)
- 120  $\mu\text{m}$  solder bump bond (GEC-Marconi)

100x92 PAD developers include:

Sandor Barna  
Eric Eikenberry  
Alper Ercan  
Sol Gruner  
Matt Renzi  
Giuseppe Rossi  
Bob Wixted



G. Rossi, *et al*, J Synchrotron Rad. (1999). 6, 1095-1105.

# 100 x 92 Prototype Tests



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## Test results with 8.9 keV x-rays

• Full well capacity (x-rays)	17000
• Non-linearity (% full well)	< 0.5 %
• RMS read noise : (x-rays/pixel)	2.0 – 2.8
• Dark current (-20 C) (x-ray/pixel/s) (fA/pixel)	1.6 – 7.7 6 – 40
• Storage capacitor leakage	0.07% / s
• PSF (@75 $\mu$ m)	< 1%
• X-rays stopped in diode	97 %
• Minimum integration period ( $\mu$ s)	0.15
• Minimum deadtime between frames ( $\mu$ s)	0.6
• Rad damage threshold (kRad in CMOS oxide)	30
• Tolerable radiation dose (kRad)	>300

# High speed radiography:

Supersonic spray from diesel fuel injector



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## X-ray beam

- CHES Beamline D-1
- 6 keV (1% bandpass)
- 2.5 mm x 13.5 mm (step sample to tile large area)
- $10^8 - 10^9$  x-rays/pix/s
- 5.13  $\mu$ s integration (2x ring period)

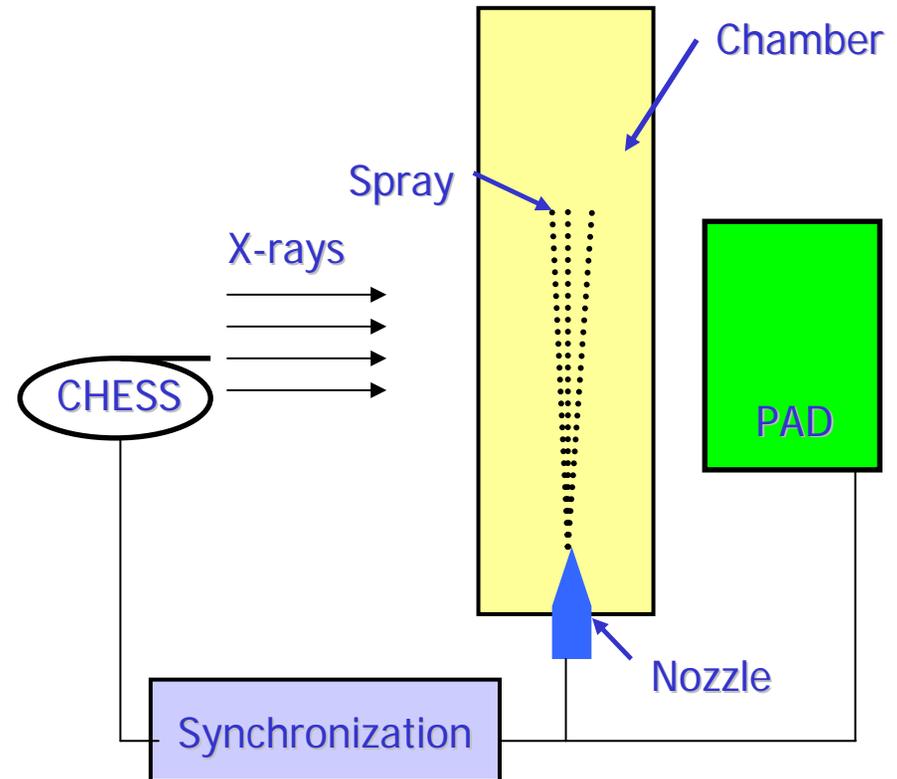
## Diesel Fuel Injection System

- Cerium added for x-ray contrast
- 1350 PSI gas driven
- 1.1 ms pulse
- 1 ATM SF<sub>6</sub> in chamber

Collaboration: Jin Wang (APS) & S.M. Gruner (Cornell)

See: McPhee, Tate, Powell, Yue, Renzi, Ercan, Narayanan, Fontes, Walther, Schaller, Gruner & Wang

*Science* 295 (2002) 1261-1263.

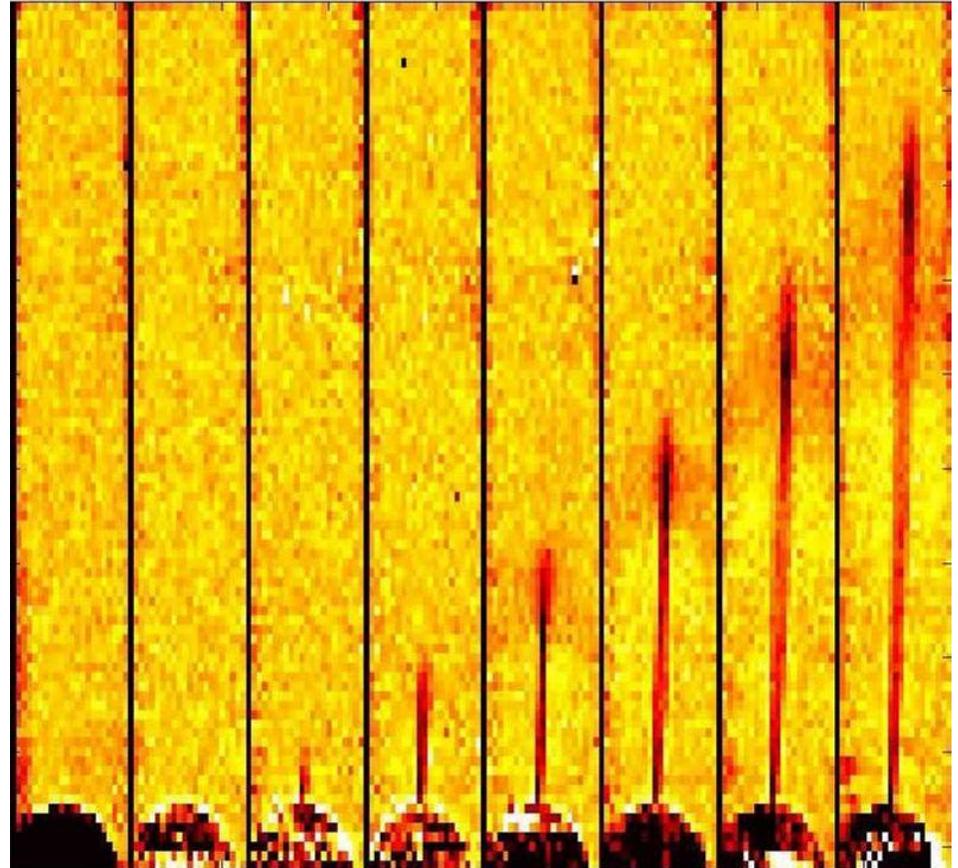
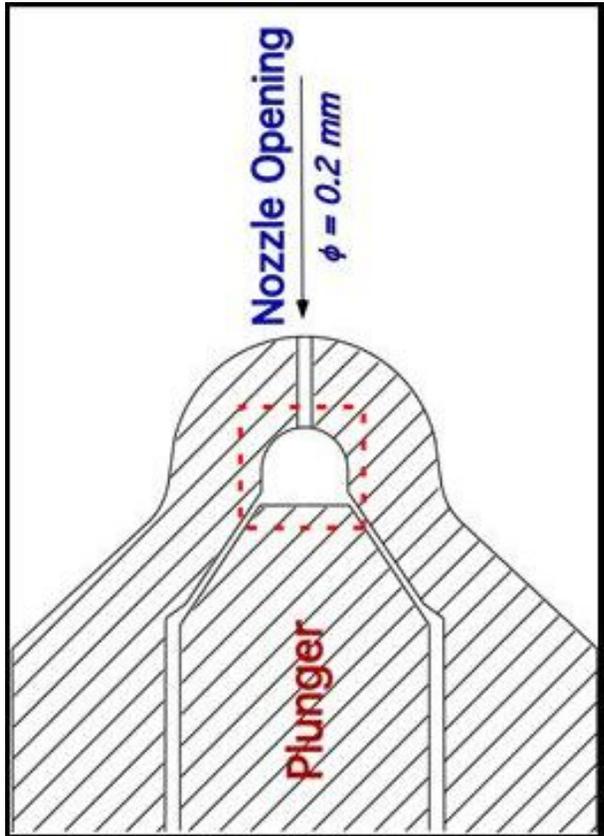


# High speed radiography:

Supersonic spray from diesel fuel injector



CHES & LASSP

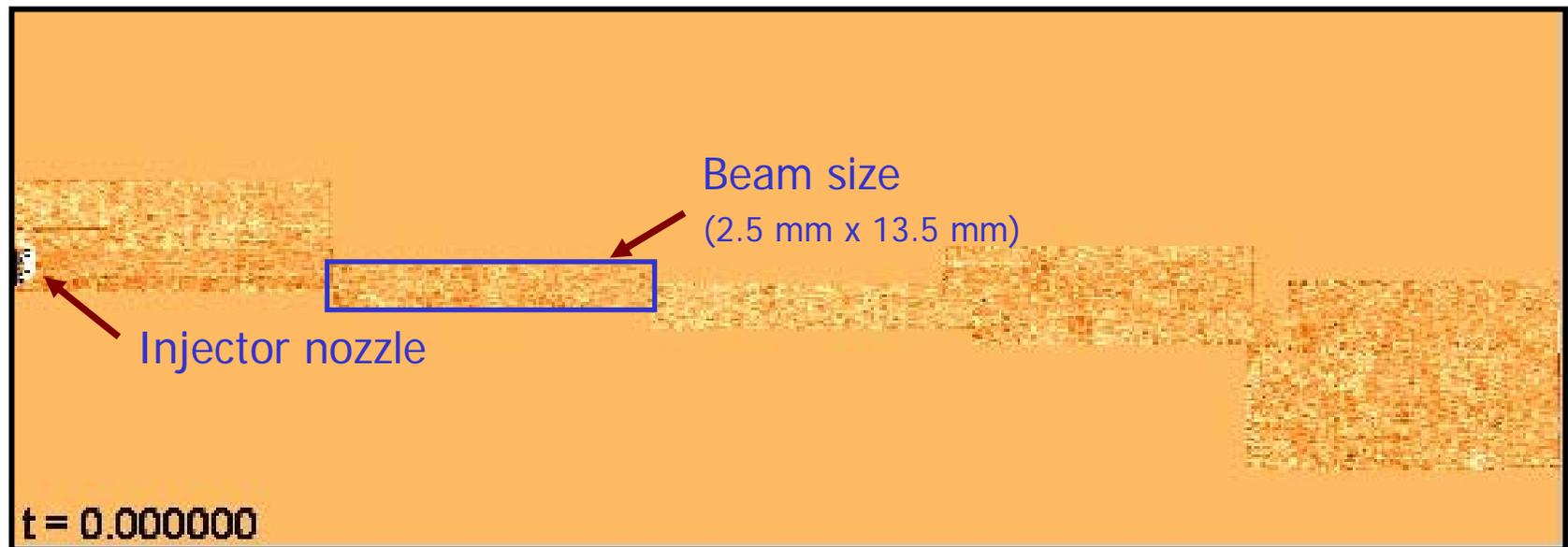


# Diesel fuel injector spray



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- 1.3 ms time sequence (composite of 34 sample positions)
- 5.13  $\mu\text{s}$  exposure time (2.56  $\mu\text{s}$  between frames)
- 168 frames in time (21 groups of 8 frames) Average 20x for S/N
- Sequence comprised of  $5 \times 10^4$  images



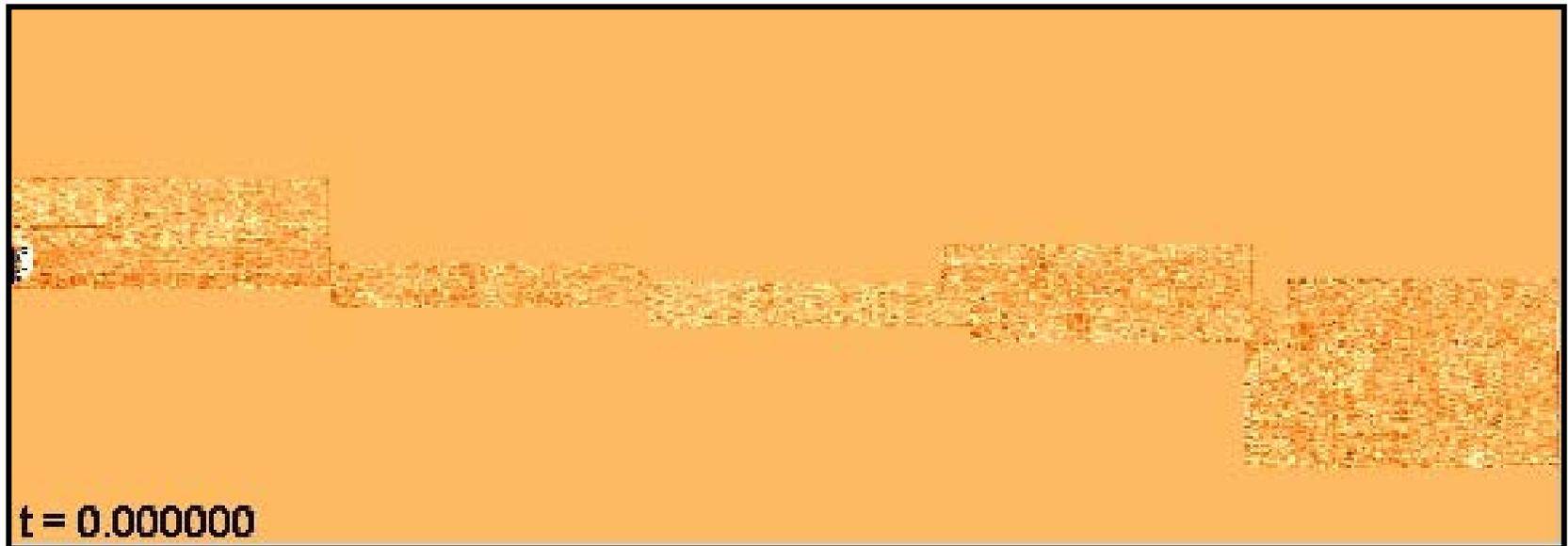
A. MacPhee, *et al*, Science (2002). **295**, 1261-1263.

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A. MacPhee, *et al*, Science (2002). **295**, 1261-1263.

# Gasoline fuel injector spray



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## X-ray beam

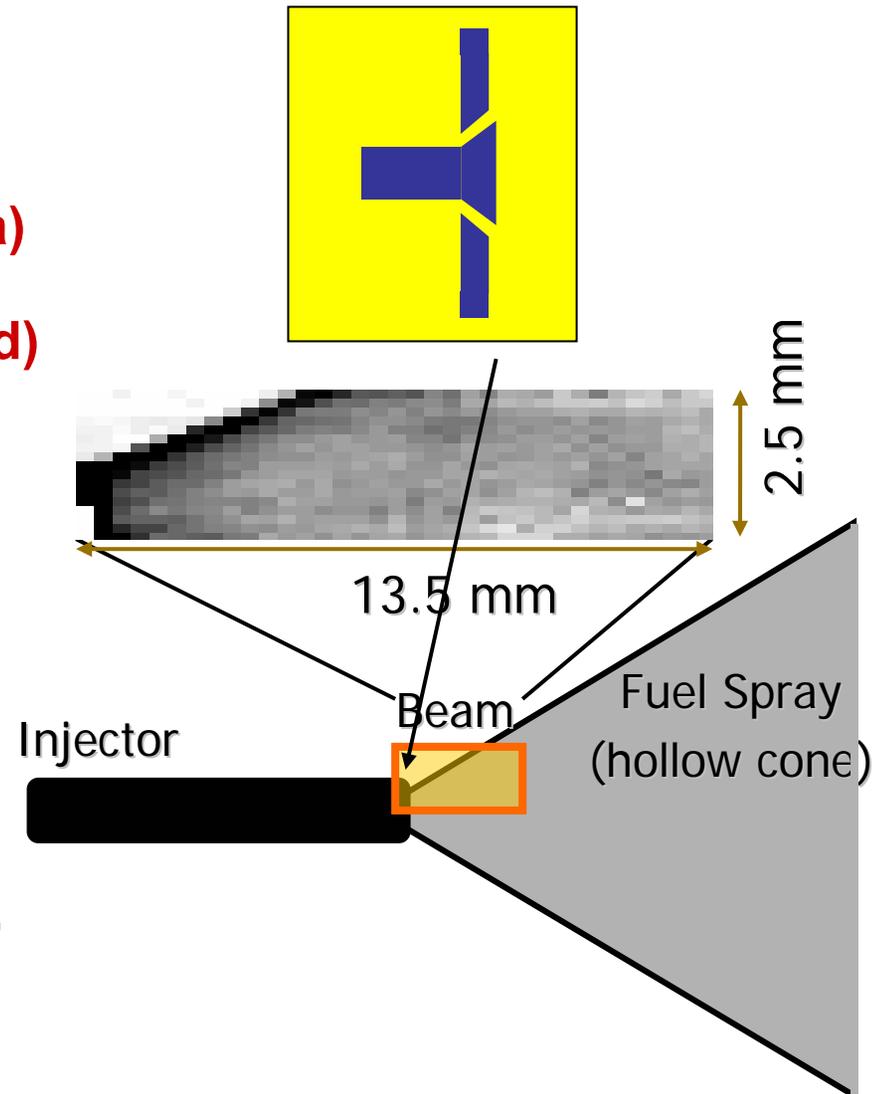
- **CHESS Beamline D-1**
- **6 keV (1% bandpass)**
- **2.5 mm x 13.5 mm**
- **(step sample to tile large area)**
- **$10^9$  x-rays/pix/s**
- **$5.13 \mu\text{s}$  integration (2x ring period)**

## Fuel injection system

- **Cerium added for x-ray contrast**
- **1000 PSI gas driven**
- **1 ms pulse**
- **1 ATM Nitrogen**

**Collaboration: Jin Wang (APS) & S.M. Gruner (Cornell)**

**See: Cai, Powell, Yue, Narayanan, Wang, Tate, Renzi, Ercan, Fontes & Gruner  
Appl. Phys. Lett. (in press, 2003)**

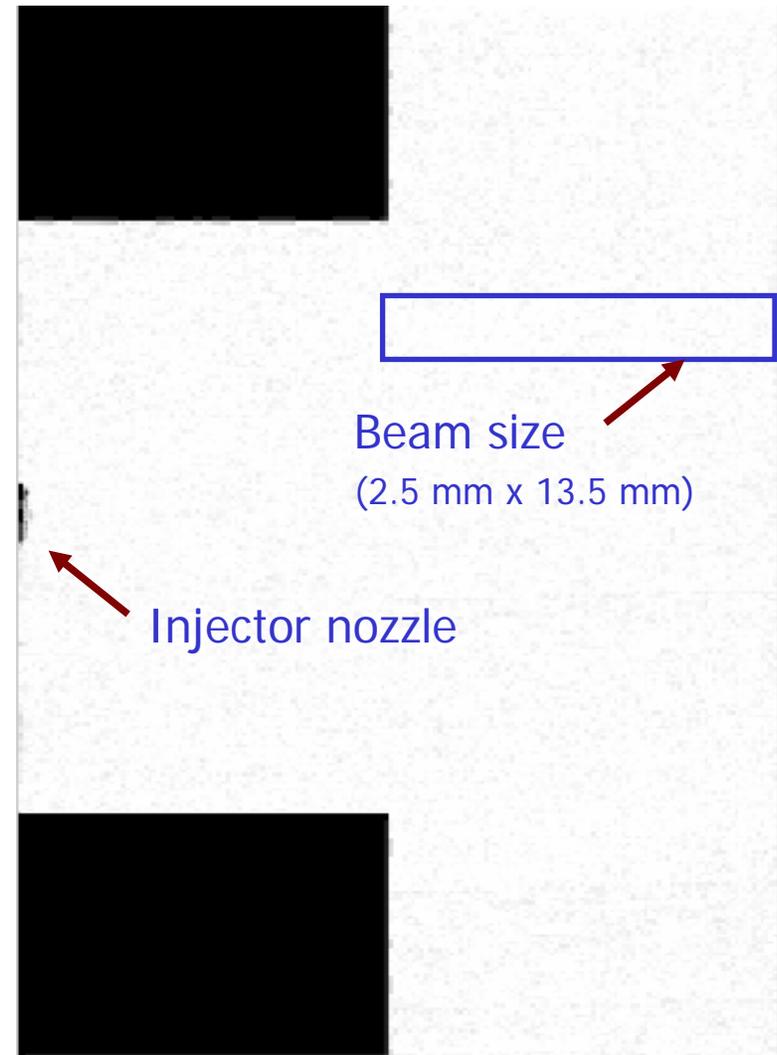


# Gasoline fuel injector spray



CHESS &amp; LASSP

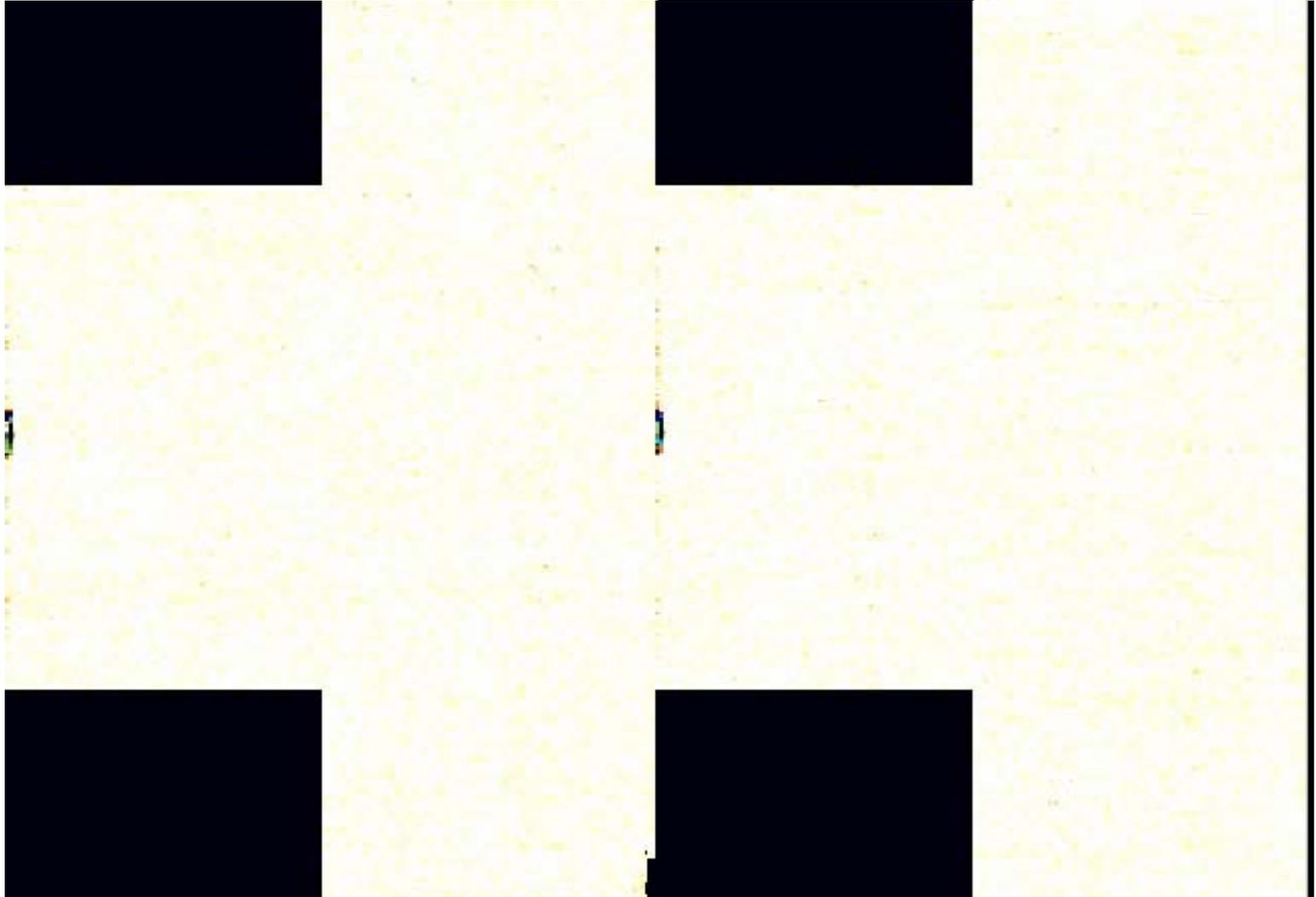
- 1.8 ms time sequence (composite)
- 5.13  $\mu\text{s}$  exposure time
- (15.4  $\mu\text{s}$  between frames)
- 88 frames (11 groups of 8 frames)
- 28 beam positions
- 1000 x-rays/pixel/ $\mu\text{s}$
- Average 20x to improve S/N
- Data taken with 4 projections (2 will be shown)
- Sequence comprised of  $10^5$  images



# Gasoline fuel injector spray



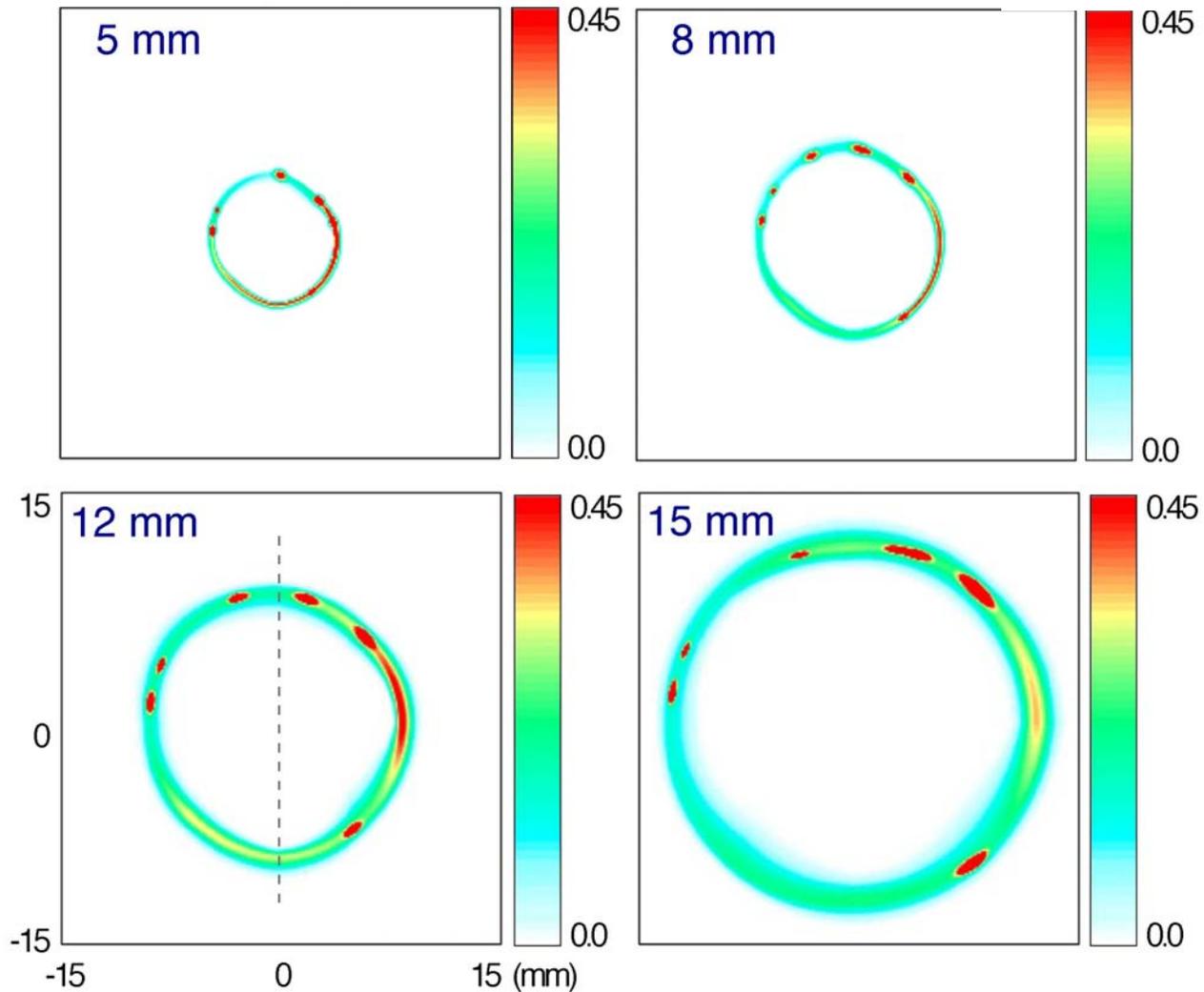
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# Spray is very nonuniform



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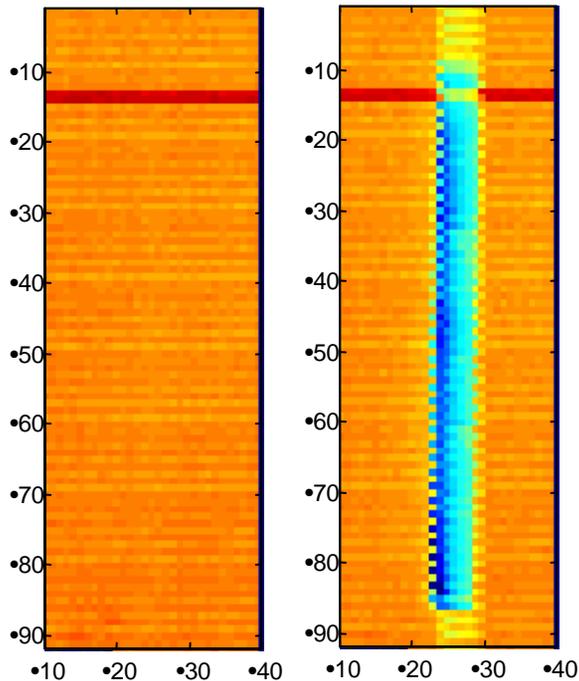
# Radiation Damage (1.2 $\mu\text{m}$ chip)



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## Background images

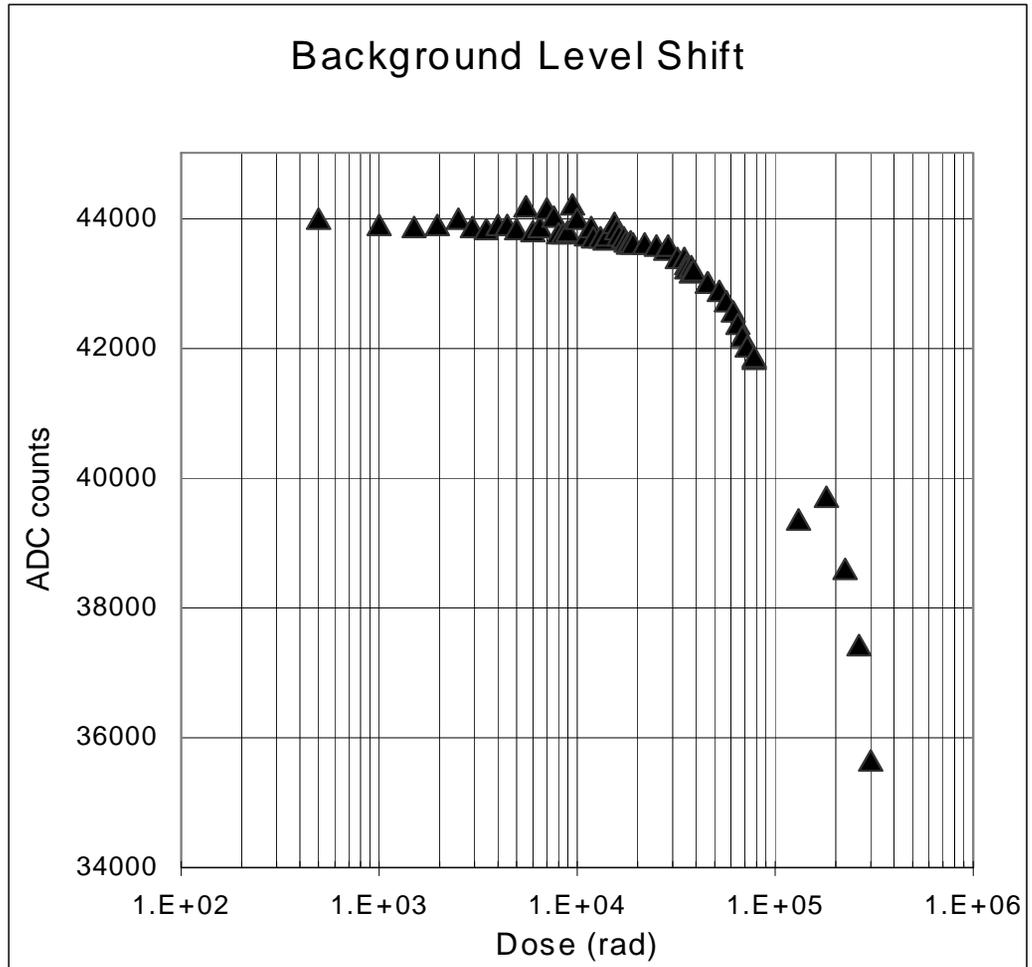
original      300 kRad to oxide



Background level shift  
(correctable)

However- losing full well

## Background Level Shift

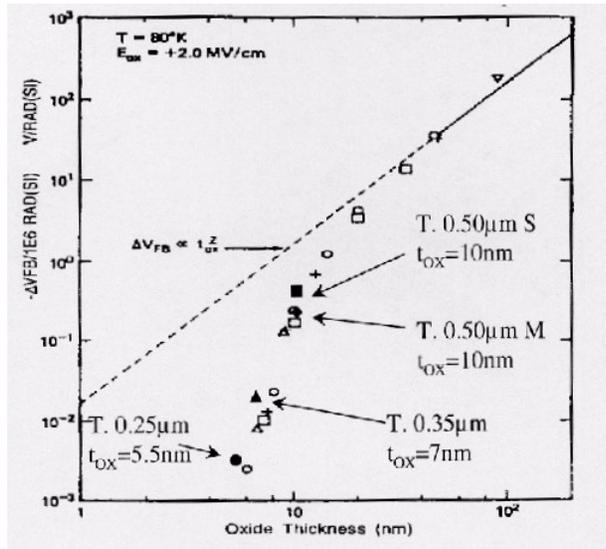
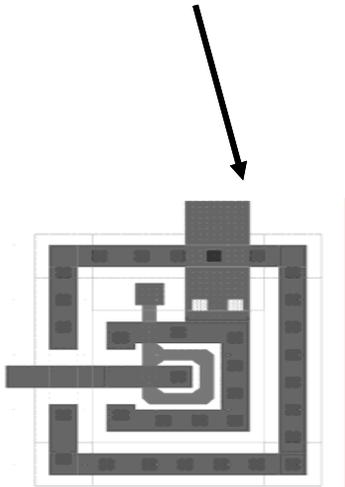


# Improvements in Radiation Tolerance



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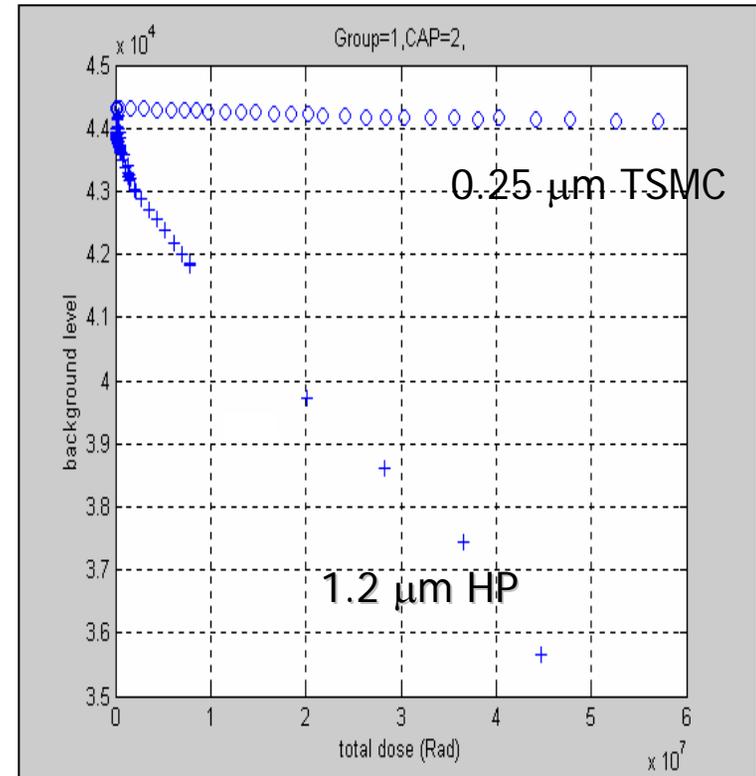
1. Thinner CMOS oxide
2. Enclosed (ring) gates



Saks et al., IEEE Trans. Nuc. Sci **33** (1986) 1185.

Bkgnd level of amplifier in 16x16 pix detector (enclosed gates, 0.25μm TSMC process).

Still good after 60 MRad to detector.

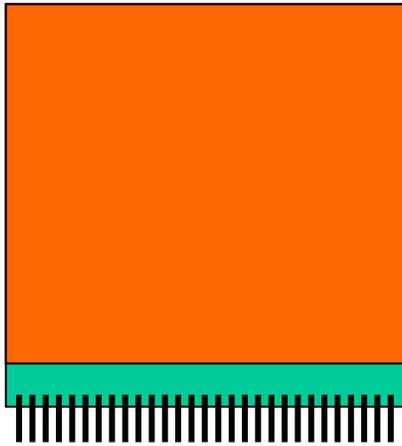


# Tiling for larger area



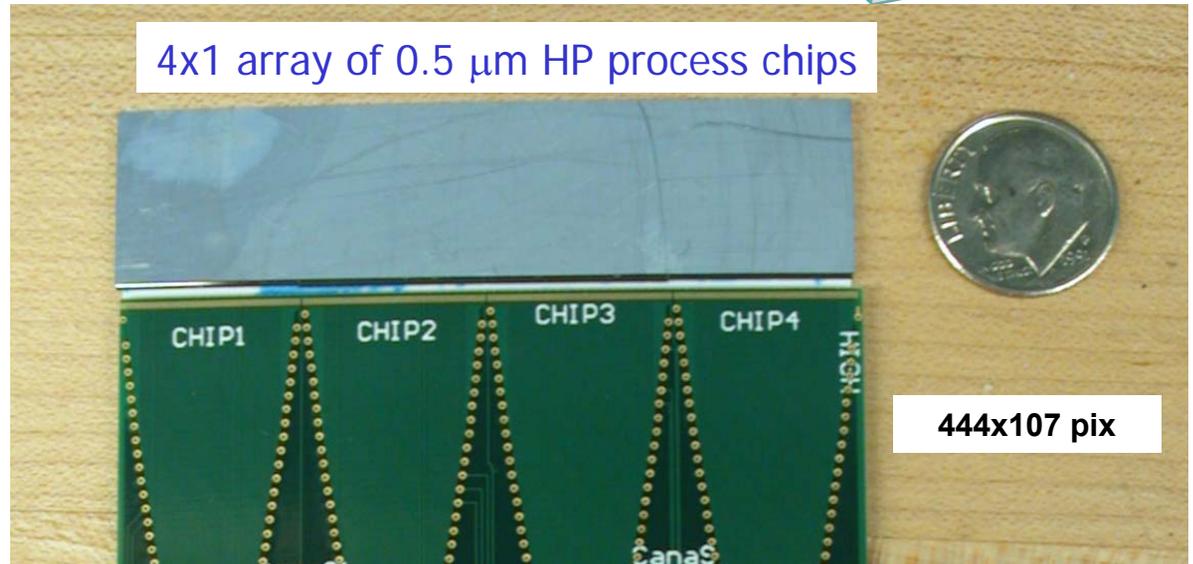
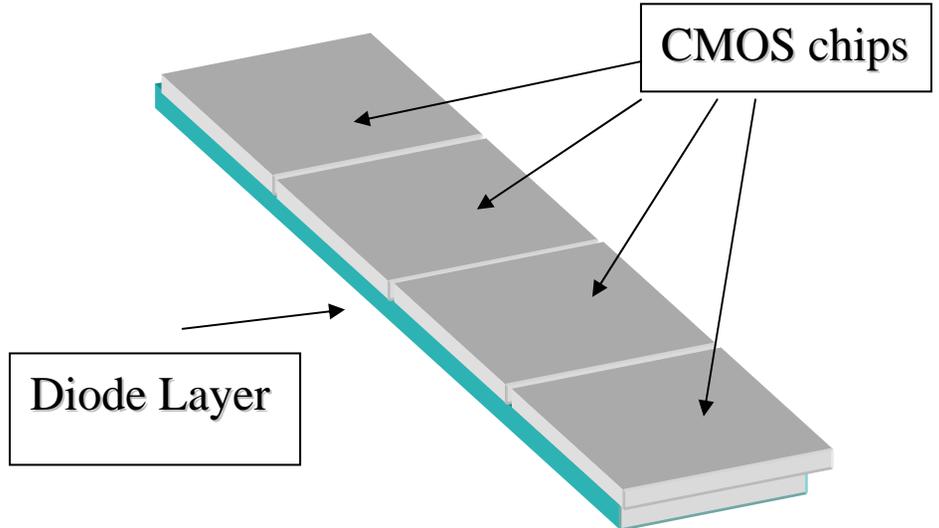
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**Use 3 side buttable CMOS dies:**



**4 chips on larger diode array**  
(arrays also 3 side buttable)

**3 pixel gap between chips**



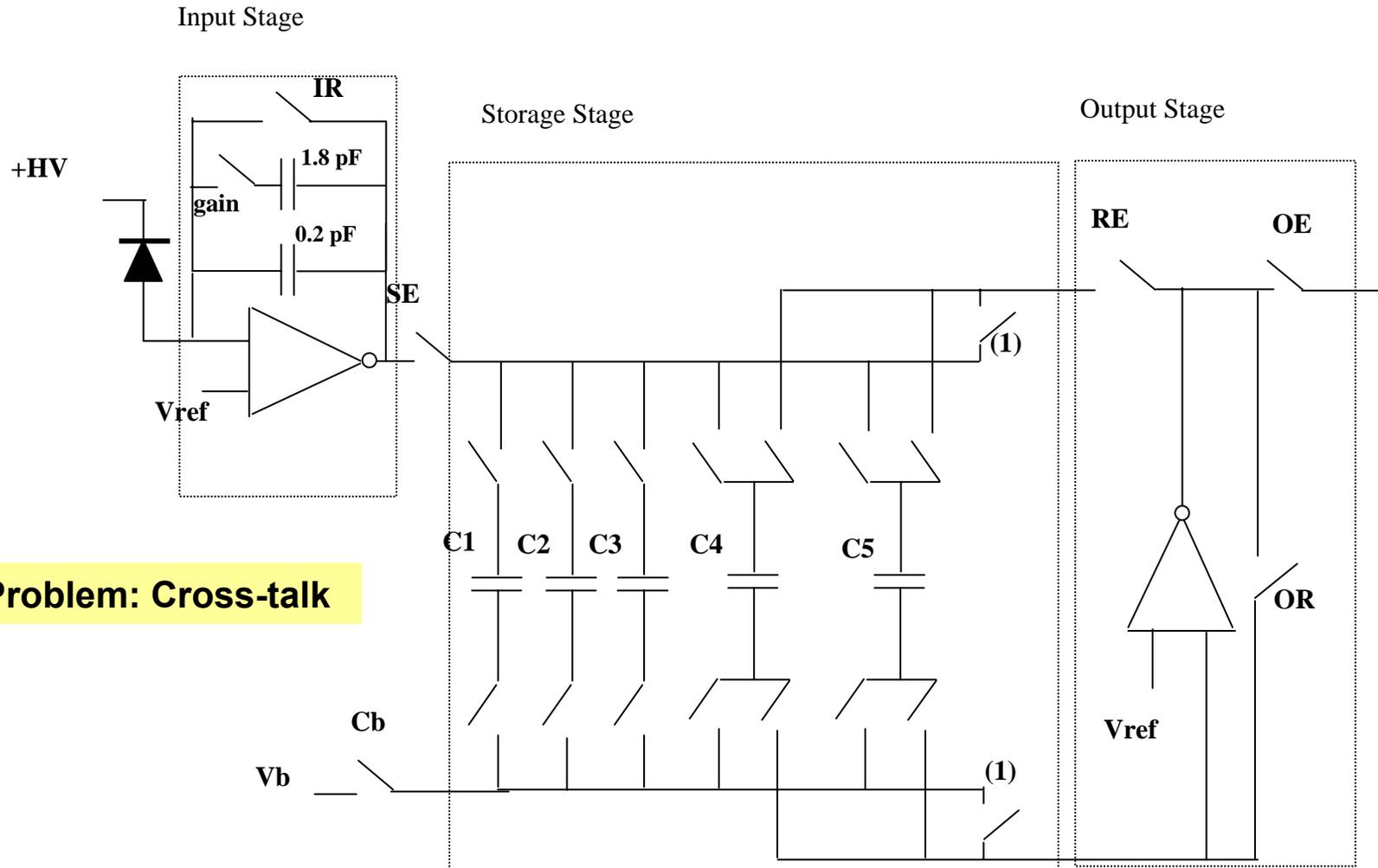
4x1 array of 0.5  $\mu\text{m}$  HP process chips

444x107 pix

# Faster Duty-Cycle: Push-Pull Configuration with Selectable Gain



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**Problem: Cross-talk**

# What do we really want for most experiments?

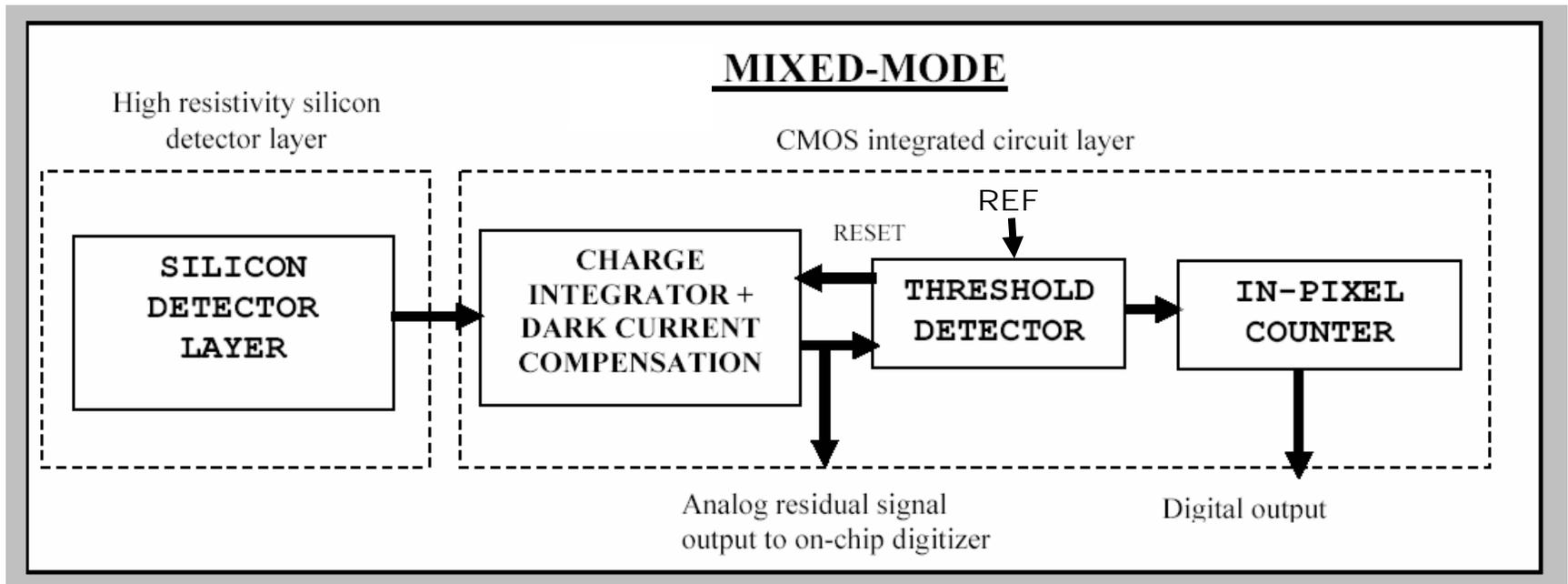


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**Answer:** For a given slice of time, a 2-dimensional floating-point array of numbers that maps the x-ray intensity over a given imaging surface.

**Question:** Given this, how many digits should there be in the mantissa?

**Answer:** Relative accuracy of existing detectors almost never exceeds 0.2% and, typically barely achieves 1%. Suggests an 8 bit mantissa.



1. Charge integrated up to some max level, set by threshold,  $Q_T$ .
2. When  $Q_T$  is reached, a bit is added into in-pix digital counter, and the integrator is zeroed.
3. Upon command, the total count is output. The remaining charge in the integrator is digitized, if desired. One ADC/row.



MMPAD principally characterized by few critical parameters:

- $G \equiv$  Charge-to-voltage input amp conversion gain
- $V_{REF} \equiv$  Threshold for zeroing analog integrator
- $V \equiv$  Voltage range allowed by fabrication process
- $C_{INT} \equiv$  Size of integration capacitor
- $M_{ADC} \equiv$  # bits of on-chip ADC
- $N_{DIG} \equiv$  # bits of in-pix digital counter
- $\sigma \equiv$  Total pixel noise

**Straightforward to model pixel for given parameters.**

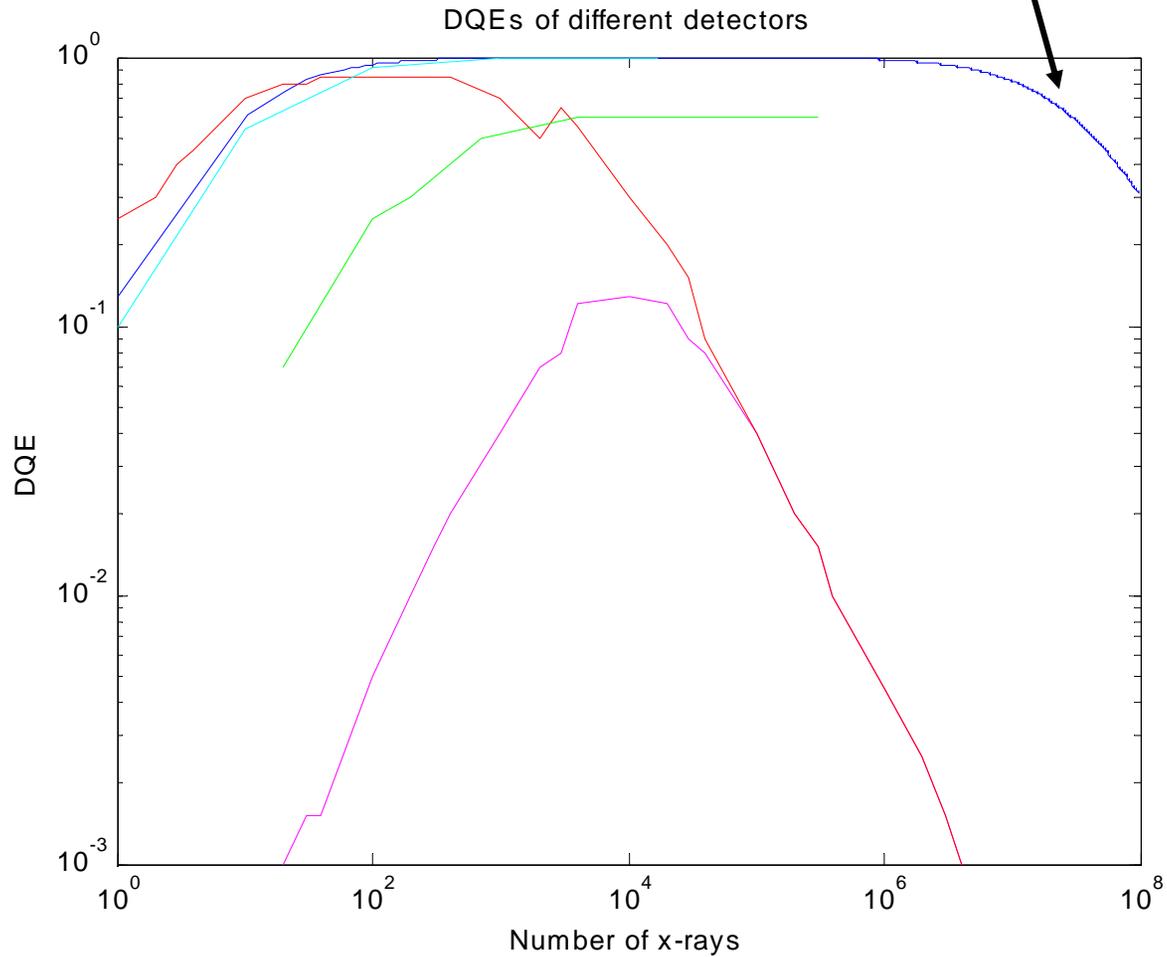
**Note:  $N_{DIG} = 0$  equivalent to traditional analog PAD.**

**$V_{REF} = 1$  x-ray,  $M_{ADC} = 0$  is traditional photon counter.**

# Theoretical DQE of MMPAD



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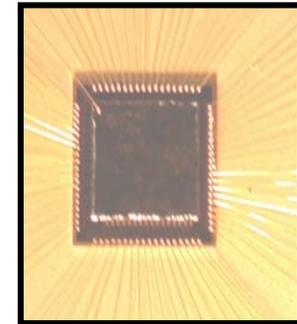
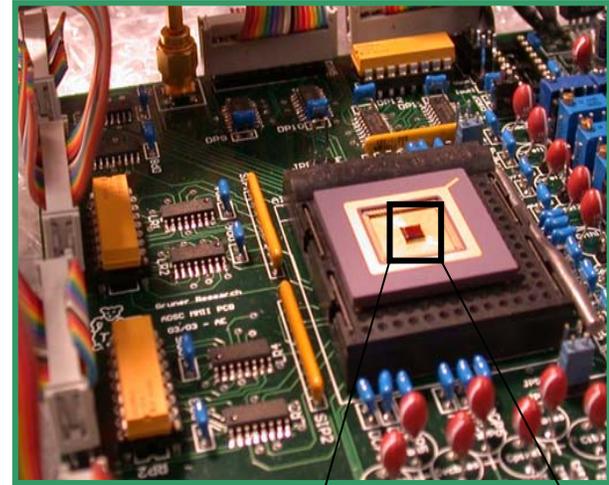
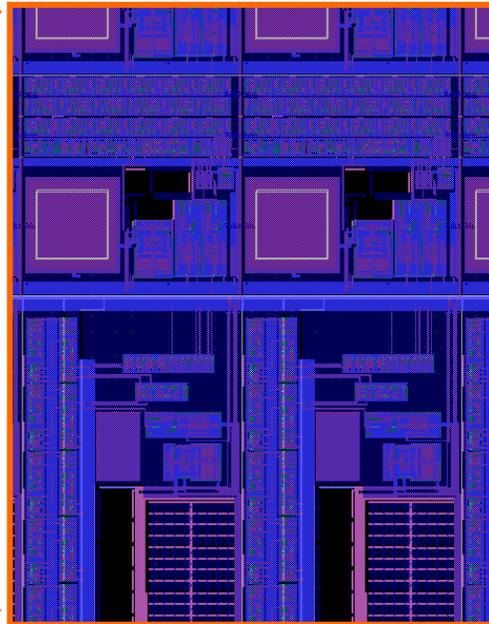
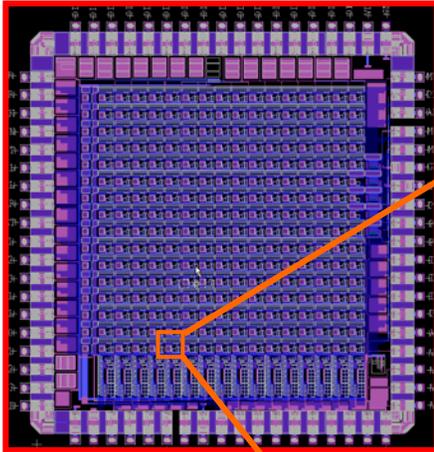


DQE assuming 100% diode layer stopping power

# First 16x16 MMPAD test chips



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# S ummary



- **Prototype analog PAD already useful for cutting edge science.**
- **Many variations on CMOS possible.**
- **Consideration of way image data is actually analyzed suggests MMPAD has advantages of both analog and photon-counting PADs.**
- **First MMPAD test chips have been made.**
- **Years of work remain (packaging, tiling, rad-damage mitigation, etc.), but no show-stoppers.**